

In-sung Kim et al.

SEC.747

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

#3/a
10/29/00
V. Vannale

In re Patent Application of :

In-sung Kim et al. :

Attn: Applications Branch

Serial No. [NEW] :

Attorney Docket No. SEC.747

Filed: August 18, 2000 :

For: SEMICONDUCTOR DEVICE HAVING SELF-ALIGNED CONTACT AND
METHOD OF FABRICATING THE SAME

PRELIMINARY AMENDMENT

Honorable Assistant Commissioner
of Patents and Trademarks,
Washington, D.C. 20231

Sir:

Preliminary to the examination of the above-identified application, please enter
the following amendments and remarks.

IN THE CLAIMS

Please amend the claims as follows:

10. (Amended) The method of claim 9, wherein the [of] removing of portions of
the first and second interlayer dielectric layers comprises:
forming a photosensitive film pattern on the second interlayer dielectric layer, the
photosensitive film pattern defining an opening therein having widths, in two orthogonal
X and Y directions, that are greater than the critical dimension of and the width of the
gap in the conductive line, respectively, and

On
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